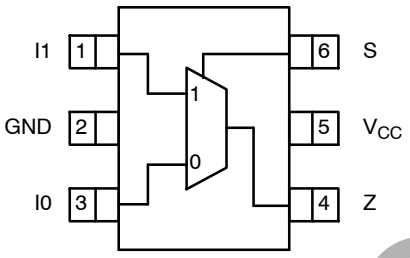
TinyLogic ULP-A 2-Input Non-Inverting Multiplexer

NC7SP157

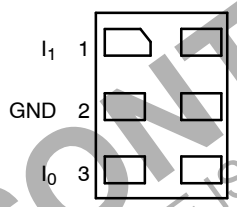
The NC7SP157 is a 2−input non−inverting multiplexer in tiny footprint packages. The device is designed to operate for V_{CC} = 0.9 V to 3.6 V.

Features

- Designed for 0.9 V to 3.6 V V_{CC} Operation
- 2.9 ns t_{PD} at 3.3 V (Typ)
- Inputs/Outputs Over−Voltage Tolerant up to 3.6 V
- I_{OFF} Supports Partial Power Down Protection
- Source/Sink 2.6 mA at 3.3 V
- Available in SC−88 and MicroPak™ Packages
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant



SC−88



MicroPak

Figure 1. Pinout Diagrams (Top Views)

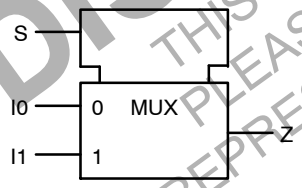


Figure 2. Logic Symbol

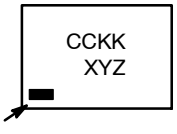
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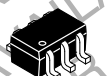
MARKING DIAGRAMS



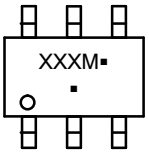
SIP6 1.45X1.0 MicroPak CASE 127EB



CC = Specific Device Code
KK = 2−Digit Lot Run Traceability Code
XY = 2−Digit Date Code
Z = Assembly Plant Code



SC−88 DF SUFFIX CASE 419B−02



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 6 of this data sheet.

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PIN ASSIGNMENT

Pin	SC88	MicroPak
1	I1	I1
2	GND	GND
3	I0	I0
4	Z	Z
5	V_{CC}	V_{CC}
6	S	S

FUNCTION TABLE

Inputs			Output
S	**I1**	**I0**	**$Z = I0 \times \overline{S} + I1 \times S$**
L	X	L	L
L	X	H	H
H	L	X	L
H	H	X	H

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MAXIMUM RATINGS

Symbol	Characteristics		Value	Unit
V_{CC}	DC Supply Voltage		−0.5 to +4.3	V
V_{IN}	DC Input Voltage		−0.5 to +4.3	V
V_{OUT}	DC Output Voltage	Active−Mode (High or Low State) Tri−State Mode (Note 1) Power−Down Mode (V_{CC} = 0 V)	−0.5 to V_{CC} + 0.5 −0.5 to +4.3 −0.5 to +4.3	V
I_{IK}	DC Input Diode Current	V_{IN} < GND	−50	mA
I_{OK}	DC Output Diode Current	V_{OUT} < GND	−50	mA
I_{OUT}	DC Output Source/Sink Current		±50	mA
I_{CC} or I_{GND}	DC Supply Current per Supply Pin or Ground Pin		±50	mA
T_{STG}	Storage Temperature Range		−65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
T_J	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 2)	SC−88 MicroPak	377 154	°C/W
P_D	Power Dissipation in Still Air	SC−88 MicroPak	332 812	mW
MSL	Moisture Sensitivity		Level 1	−
F_R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V−0 @ 0.125 in	−
V_{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	V
$I_{Latchup}$	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri−stated.
2. Measured with minimum pad spacing on an FR4 board, using 10 mm−by−1 inch, 2 ounce copper trace no air flow per JESD51−7.
3. HBM tested to EIA / JESD22−A114−A. CDM tested to JESD22−C101−A. JEDEC recommends that ESD qualification to EIA/JESD22−A115A (Machine Model) be discontinued.
4. Tested to EIA/JESD78 Class II.

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RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	Positive DC Supply Voltage		0.9	3.6	V
V_{IN}	DC Input Voltage		0	3.6	V
V_{OUT}	DC Output Voltage	Active−Mode (High or Low State) Tri−State Mode (Note 1) Power−Down Mode (V_{CC} = 0 V)	0 0 0	V_{CC} 3.6 3.6	
T_A	Operating Temperature Range		−40	+85	°C
t_r , t_f	Input Transition Rise and Fall Time	V_{CC} = 3.3 V ± 0.3 V	0	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Unit
				Min	Typ	Max	Min	Max	
V_{IH}	High−Level Input Voltage		0.9	_	0.5	–	_	–	V
			1.1 to 1.3	0.65 x V_{CC}	–	–	0.65 x V_{CC}	–	
			1.4 to 1.6	0.65 x V_{CC}	–	–	0.65 x V_{CC}	–	
			1.65 to 1.95	0.65 x V_{CC}	–	–	0.65 x V_{CC}	–	
			2.3 to 2.7	1.6	–	–	1.6	–	
			3.0 to 3.6	2.1	–	–	2.1	–	
V_{IL}	Low−Level Input Voltage		0.9	–	0.5	–	–	–	V
			1.1 to 1.3	–	–	0.35 x V_{CC}	–	0.35 x V_{CC}	
			1.4 to 1.6	–	–	0.35 x V_{CC}	–	0.35 x V_{CC}	
			1.65 to 1.95	–	–	0.35 x V_{CC}	–	0.35 x V_{CC}	
			2.3 to 2.7	–	–	0.7	–	0.7	
			3.0 to 3.6	–	–	0.9	–	0.9	
V_{OH}	High−Level Output Voltage	V_{IN} = V_{IH} or V_{IL}							V
		I_{OH} = −20 μA	0.9	–	V_{CC} − 0.1	–	–	–	
			1.1 to 1.3	V_{CC} − 0.1	–	–	V_{CC} − 0.1	–	
			1.4 to 1.6	V_{CC} − 0.1	–	–	V_{CC} − 0.1	–	
			1.65 to 1.95	V_{CC} − 0.1	–	–	V_{CC} − 0.1	–	
			2.3 to 2.7	V_{CC} − 0.1	–	–	V_{CC} − 0.1	–	
			3.0 to 3.6	V_{CC} − 0.1	–	–	V_{CC} − 0.1	–	
		I_{OH} = −0.5 mA	1.1 to 1.3	0.75 x V_{CC}	–	–	0.70 x V_{CC}	–	
		I_{OH} = −1 mA	1.4 to 1.6	1.07	–	–	0.99	–	
		I_{OH} = −1.5 mA	1.65 to 1.95	1.24	–	–	1.22	–	
		I_{OH} = −2.1 mA	2.3 to 2.7	1.95	–	–	1.87	–	
		I_{OH} = −2.6 mA	3.0 to 3.6	2.61	–	–	2.55	–	
V_{OL}	Low−Level Output Voltage	V_{IN} = V_{IH} or V_{IL}							V
		I_{OL} = 20 μA	0.9	–	0.1	–	–	–	
			1.1 to 1.3	–	–	0.1	–	0.1	
			1.4 to 1.6	–	–	0.1	–	0.1	
			1.65 to 1.95	–	–	0.1	–	0.1	
			2.3 to 2.7	–	–	0.1	–	0.1	
			3.0 to 3.6	–	–	0.1	–	0.1	
		I_{OL} = 0.5 mA	1.1 to 1.3	–	–	0.3 x V_{CC}	–	0.3 x V_{CC}	
		I_{OL} = 1 mA	1.4 to 1.6	–	–	0.31	–	0.37	
		I_{OL} = 1.5 mA	1.65 to 1.95	–	–	0.31	–	0.35	
		I_{OL} = 2.1 mA	2.3 to 2.7	–	–	0.31	–	0.33	
		I_{OL} = 2.6 mA	3.0 to 3.6	–	–	0.31	–	0.33	
I_{IN}	Input Leakage Current	V_{IN} = 0 V to 3.6 V	0.9 to 3.6	–	–	±0.1	–	±0.5	μA
I_{OFF}	Power Off Leakage Current	V_{IN} = 0 V to 3.6 V or V_{OUT} = 0 V to 3.6 V	0	–	–	0.5	–	0.5	μA
I_{CC}	Quiescent Supply Current	V_{IN} = V_{CC} or GND	0.9 to 3.6	–	–	0.9	–	0.9	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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AC ELECTRICAL CHARACTERISTICS

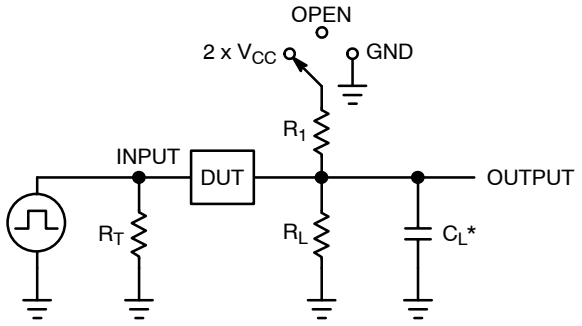
Symbol	Parameter	Condition	V_{CC} (V)	T_A = 25°C			T_A = −40°C to +85°C		Unit
				Min	Typ	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay, (S or I0 or I1) to Z (Figures 3 and 4)	R_L = 1 MΩ, C_L = 10 pF	0.9	–	54.5	–	–	–	ns
			1.10 to 1.30	–	14.6	32.3	–	37.7	
			1.40 to 1.60	–	7.6	15.1	–	16.8	
			1.65 to 1.95	–	5.4	11.5	–	12.5	
			2.3 to 2.7	–	3.6	8.1	–	9.1	
			3.0 to 3.6	–	2.9	6.6	–	7.7	
t_{PLH}, t_{PHL}	Propagation Delay, (S or I0 or I1) to Z (Figures 3 and 4)	R_L = 1 MΩ, C_L = 15 pF	0.9	–	55.9	–	–	–	ns
			1.10 to 1.30	–	15.1	33.7	–	39.7	
			1.40 to 1.60	–	8.0	16.0	–	17.2	
			1.65 to 1.95	–	5.8	12.1	–	13.1	
			2.3 to 2.7	–	3.8	8.6	–	9.7	
			3.0 to 3.6	–	3.1	7.0	–	8.1	
t_{PLH}, t_{PHL}	Propagation Delay, (S or I0 or I1) to Z (Figures 3 and 4)	R_L = 1 MΩ, C_L = 30 pF	0.9	–	60.2	–	–	–	ns
			1.10 to 1.30	–	16.7	37.8	–	47.7	
			1.40 to 1.60	–	9.3	18.6	–	19.5	
			1.65 to 1.95	–	6.9	14.1	–	15.3	
			2.3 to 2.7	–	4.5	10.0	–	11.2	
			3.0 to 3.6	–	3.7	8.2	–	9.3	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition	Typical (T_A = 25°C)	Unit
C_{IN}	Input Capacitance	V_{CC} = 0 V	2.0	pF
C_{OUT}	Output Capacitance	V_{CC} = 0 V	4.0	pF
C_{PD}	Power Dissipation Capacitance (Note 5)	f = 10 MHz, V_{CC} = 0.9 to 3.6 V, V_{IN} = 0 V or V_{CC}	8.0	pF

5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no−load dynamic power consumption: $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

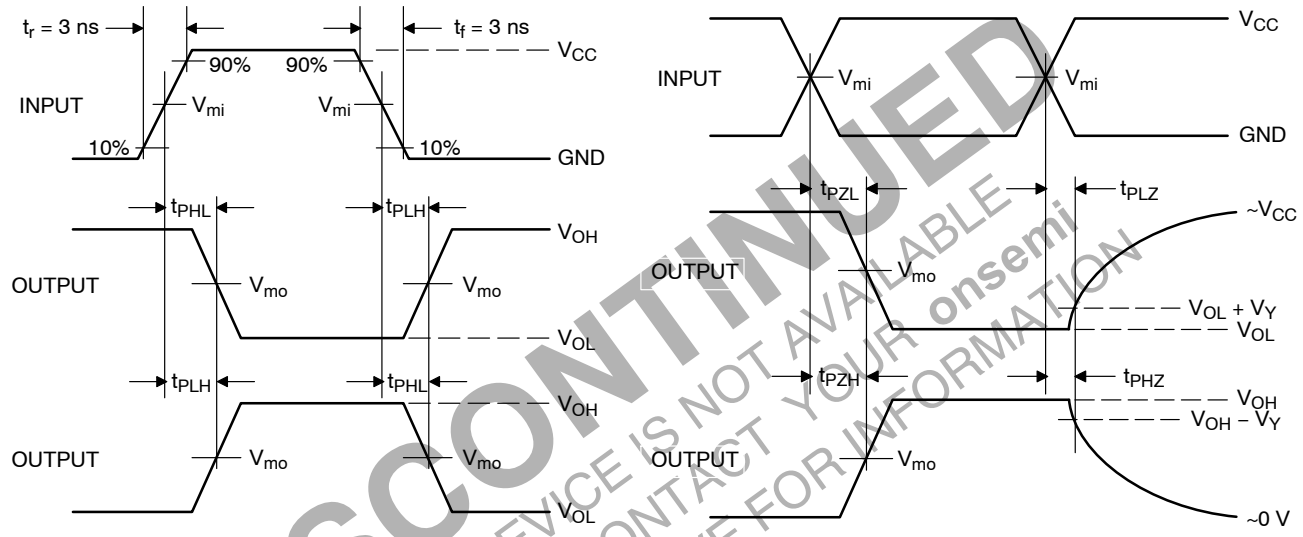
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C_L includes probe and jig capacitance
R_T is Z_{OUT} of pulse generator (typically 50 Ω)
f = 1 MHz

Test	Switch Position
t_{PLH} / t_{PHL}	Open
t_{PLZ} / t_{PZL}	2 x V_{CC}
t_{PHZ} / t_{PZH}	GND

Figure 3. Test Circuit



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V_{CC}, V	V_{mi}, V	V_{mo}, V	V_Y, V
0.9	V_{CC} / 2	V_{CC} / 2	0.1
1.1 to 1.3	V_{CC} / 2	V_{CC} / 2	0.1
1.4 to 1.6	V_{CC} / 2	V_{CC} / 2	0.1
1.65 to 1.95	V_{CC} / 2	V_{CC} / 2	0.15
2.3 to 2.7	V_{CC} / 2	V_{CC} / 2	0.15
3.0 to 3.6	1.5	1.5	0.3

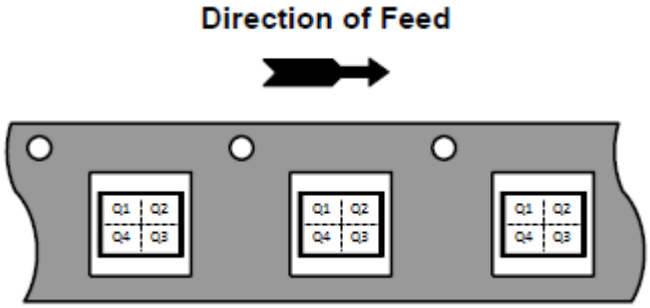
Figure 4. Switching Waveforms

ORDERING INFORMATION

Device	Package	Marking	Pin 1 Orientation (See below)	Shipping†
NC7SP157P6X	SC−88	PF7	Q4	3000 / Tape & Reel
NC7SP157L6X	MicroPak	L7	Q4	5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Pin 1 Orientation in Tape and Reel



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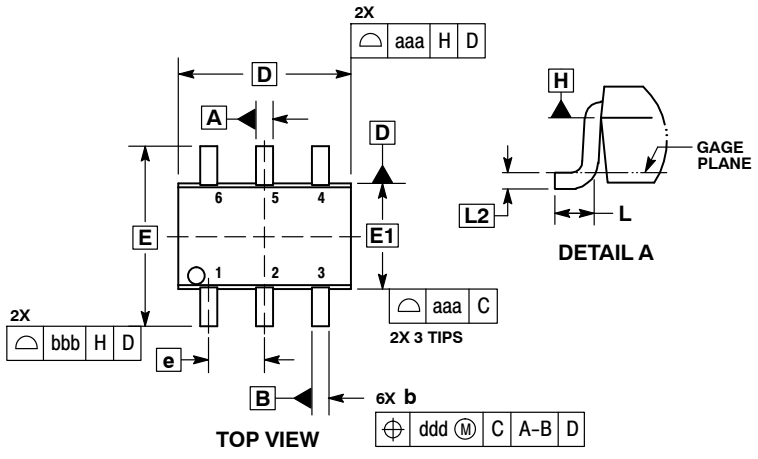
Revision	Description of Changes	Date
3	Document Discontinued.	3/11/2026

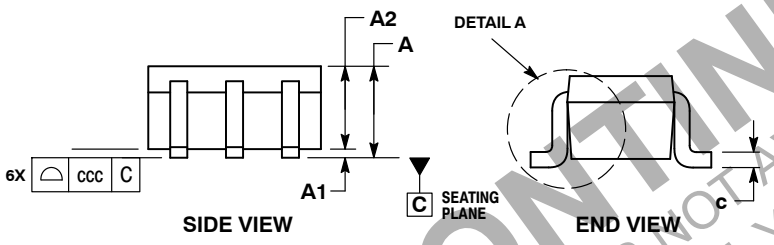
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

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PACKAGE DIMENSIONS

SC−88/SC70−6/SOT−363
CASE 419B−02
ISSUE Y





NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END.
4. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H.
5. DATUMS A AND B ARE DETERMINED AT DATUM H.
6. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
7. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION b AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
A	---	---	1.10	---	---	0.043
A1	0.00	---	0.10	0.000	---	0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.010
C	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.070	0.078	0.086
E	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65 BSC			0.026 BSC		
L	0.26	0.36	0.46	0.010	0.014	0.018
L2	0.15 BSC			0.006 BSC		
aaa	0.15			0.006		
bbb	0.30			0.012		
ccc	0.10			0.004		
ddd	0.10			0.004		

RECOMMENDED SOLDERING FOOTPRINT*



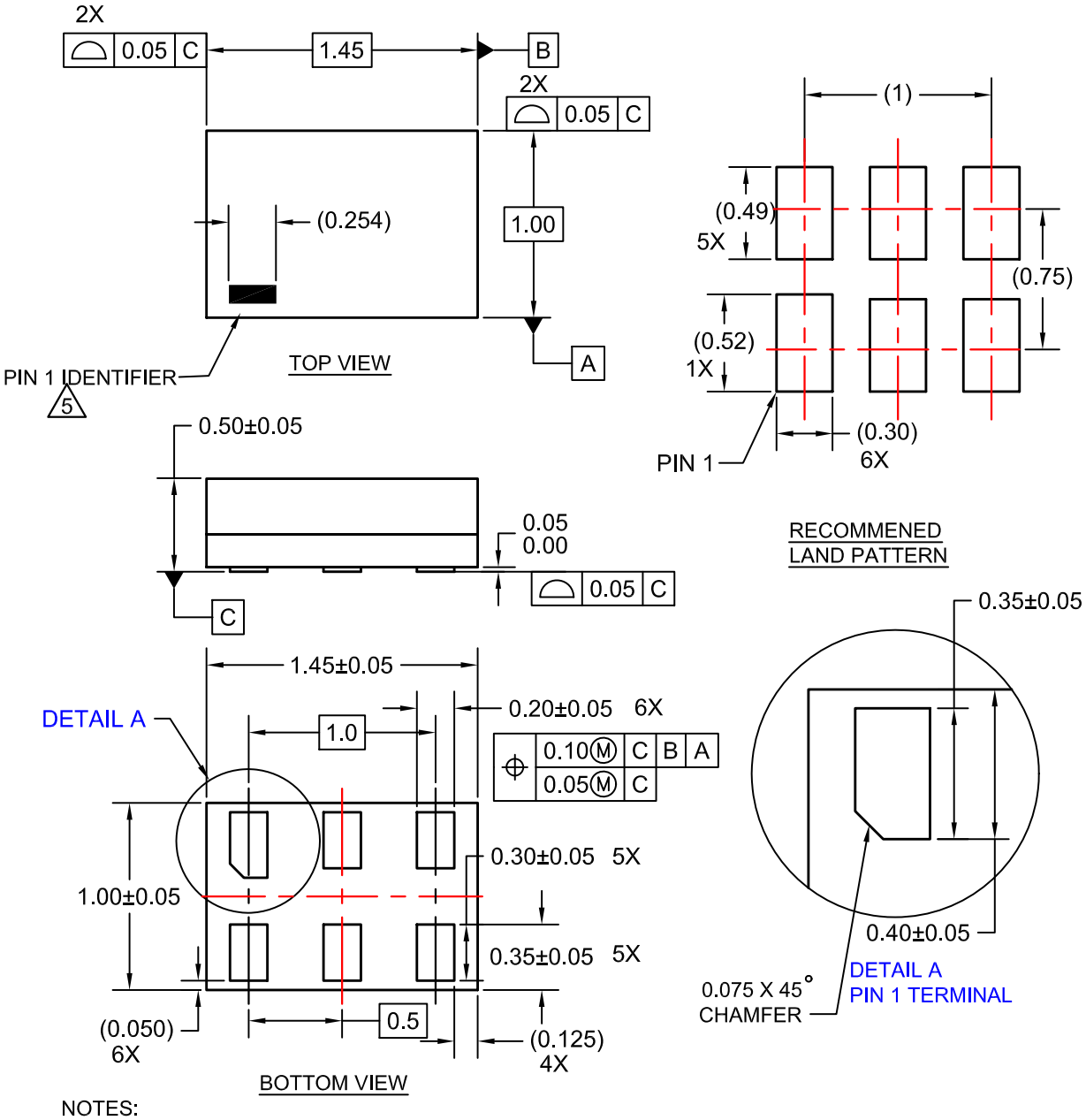
DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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SIP6 1.45X1.0
CASE 127EB
ISSUE O

DATE 31 AUG 2016



NOTES:

1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
2. DIMENSIONS ARE IN MILLIMETERS
3. DRAWING CONFORMS TO ASME Y14.5M-2009
4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY OTHER LINE IN THE MARK CODE LAYOUT.

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DESCRIPTION:	**SIP6 1.45X1.0**	**PAGE 1 OF 1**

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